



A Product Line of **Diodes Incorporated**

LITE-ON SEMICONDUCTOR

G30C100CTW

TRENCH SCHOTTKY RECTIFIER		REVERSE VOLTAGE – 100 Volts FORWARD CURRENT – 30 Amperes		
 FEATURES High efficiency Reduced high temperature reverse leakage Reduced ultra-low forward voltage drop Qualification is according to AEC-Q101 Rev_C Lead-Free Finish; RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3) APPLICATION DC to DC converters AC to DC adaptors MECHANICAL DATA Package: JEDEC TO-220AB Package Material: "Green" molding compound, UL flamm classification 94V-0, "Halogen-free". Lead free finish, RoHS compliant Weight: 1.927 grams (Approximate) Marking code: G30C100CTW MAXIMUM RATINGS AND ELECTRICAL CHARACTER Ratings at 25°C ambient temperature unless otherwise statings at 25°C ambient temperature unless otherwise	nability RISTICS specified.	TO-220A	TO-220AB DIM MIN MAX A 14.40 15.20 B 9.65 10.67 C 2.54 3.43 D 5.84 6.86 E 8.26 9.28 F 4.20 G 12.70 14.73 H 2.29 2.79 I 0.51 1.00 J 0.30 0.64 K 3.53Φ 4.09Φ L 3.56 4.83 M 1.14 1.40 N 2.03 2.92 O 1.14 1.37 All Dimensions in millimeter All Dimensions in millimeter	
PARAMETER	SYMBOL	VALUE	UNIT	

PARAMETER		VALUE	UNIT
Maximum repetitive peak reverse voltage		100	V
Maximum DC blocking voltage		100	V
Maximum Average rectified output current @T _c =120°C		30	А
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load.		250	А
Non repetitive peak reverse current @tp=2us		3	А
Operating junction and Storage Temperature range		-55 ~ +150	°C
	@tp=2us	@tp=2us I _{RSM}	$\begin{tabular}{ c c c c c c c c c c c c c c c c c c c$

STATIC ELECTRICAL CHARACTERISTICS

PARAMETER TEST		TEST CONDITIONS SYMBOL		TYP	MAX	UNIT
Forward voltage (Note 4)	I _F =2A	T _J =25°C		0.46		V
	I _F =5A	TJ=25°C	VF	0.56		
	I _F =15A	TJ=25°C TJ=125°C		 0.65	0.81 0.70	
Leakage current	V _R =100V	T _J =25°C T _J =125°C	I _R	 5.3	30 12	uA mA
Typical junction capacitance (Note 5)			CJ	370		pF

THERMAL CHARACTERISTICS

PARAMETER	SYMBOL	ТҮР	UNIT
Typical thermal resistance (Note 6, 7)	RthJ _c	1	°C/W
Typical thermal resistance (Note 0, 7)	RthJ∟	1	0/11

Note:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony

compounds.

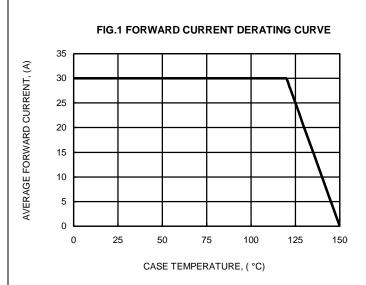
4. 300us pulse width, 2% duty cycle.
5. Measured at 1.0MHz and applied voltage of 4.0V DC.
6. Thermal resistance test performed in accordance with JESD-51.

7. The unit mounted on fin type heatsink (85mm x 32mm x 24mm).

RATING AND CHARACTERISTIC CURVES G30C100CTW

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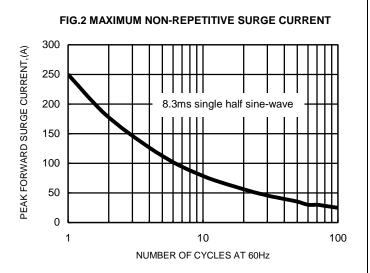
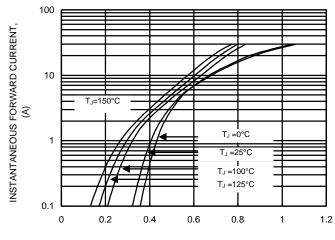


FIG.3 TYPICAL FORWARD CHARACTERISTICS



INSTANTANEOUS FORWARD VOLTAGE, (V)

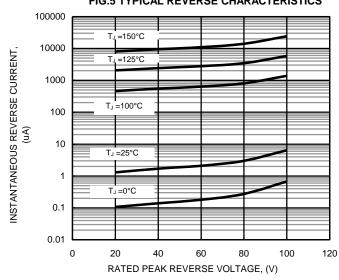
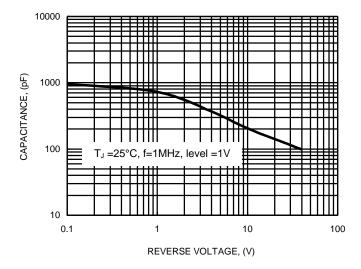


FIG.5 TYPICAL REVERSE CHARACTERISTICS

FIG.4 TYPICAL JUNCTION CAPACITANCE





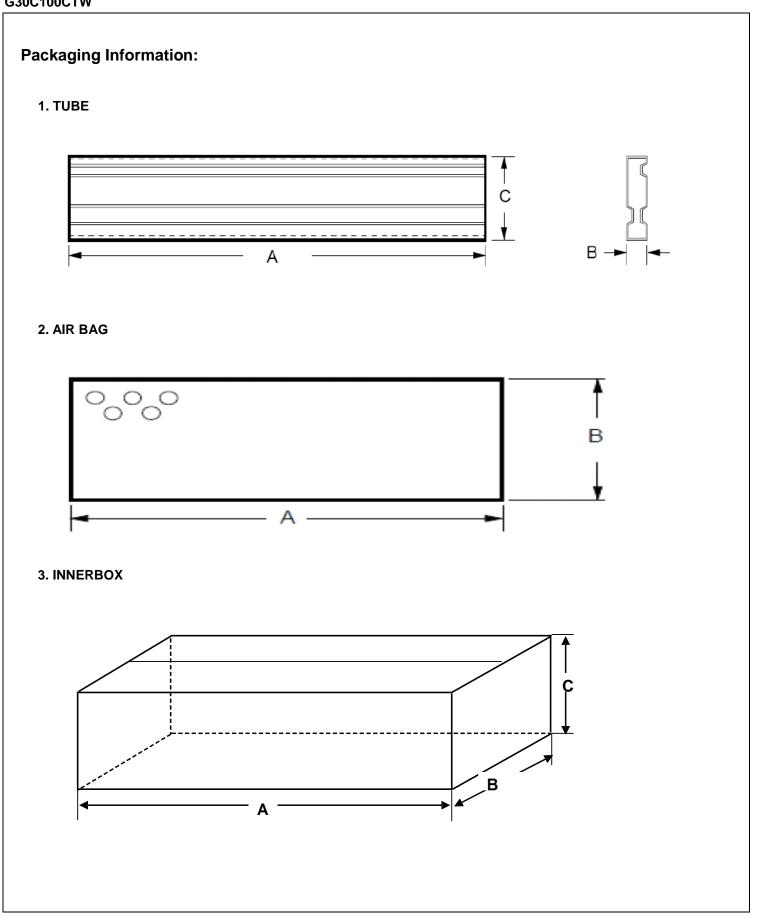
LITE-ON SEMICONDUCTOR

Ordering Information:

Part Number		Deskers	Packing	
Part Numbe	er	Package	Qty.	Carrier
G30C100CT	G30C100CTW		50pcs	Tube
g Information: $LOGO \longrightarrow $		/w - }	Date Code (= Year Code (= 1.2.T.R.3Manufa (= A.B.V.K.CGreen VW = Week Code Product Type Marking (Compound



LITE-ON SEMICONDUCTOR

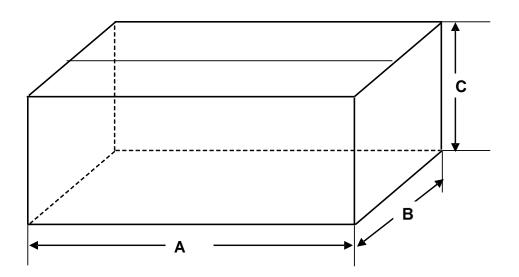




LITE-ON SEMICONDUCTOR

Packaging Information (continued):

4. CARTON



Unit: mm

P/N	DIMENSION "A"	DIMENSION "B"	DIMENSION "C"	Q'ty/per	REMARK
TUBE	536	5.6	31.8	50	1
AIR BAG	800	550	1	1	1
INNERBOX	555	165	105	2000	40TUBE
CARTON	575	179	225	4K	2 INNER BOX





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